

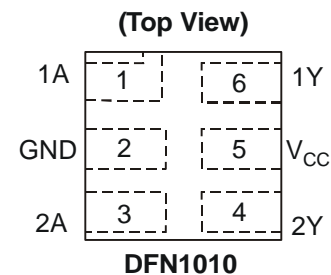
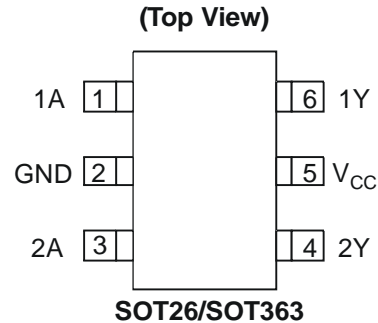
## Description

The 74LVC2G04 is a dual inverter gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = \overline{A}$$

## Pin Assignments



## Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.0V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- SOT26, SOT363, and DFN1010 Available in “Green” Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

## Applications

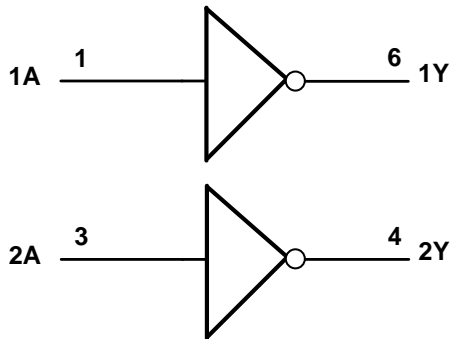
- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - Cell Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at [http://www.diodes.com/products/lead\\_free.html](http://www.diodes.com/products/lead_free.html).

### Pin Descriptions

Pin Name	Pin NO.	Description
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
V <sub>CC</sub>	5	Supply Voltage
1Y	6	Data Output

### Logic Diagram



### Function Table

Inputs	Output
A	Y
H	L
L	H

### Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	ESD Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
$V_{CC}$	Supply Voltage Range	-0.5 to 6.5	V
$V_I$	Input Voltage Range	-0.5 to 6.5	V
$V_O$	Voltage applied to output in high impedance or $I_{OFF}$ state	-0.5 to 6.5	V
$V_O$	Voltage applied to output in high or low state.	-0.3 to $V_{CC} + 0.5$	V
$I_{IK}$	Input Clamp Current $V_I < 0$	-50	mA
$I_{OK}$	Output Clamp Current	-50	mA
$I_O$	Continuous output current	$\pm 50$	mA
	Continuous current through Vdd or GND	$\pm 100$	mA
$T_J$	Operating Junction Temperature	-40 to 150	$^{\circ}C$
$T_{STG}$	Storage Temperature	-65 to 150	$^{\circ}C$

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

### Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Operating Voltage	Operating	1.65	5.5	V
		Data retention only	1.5		V
V <sub>IH</sub>	High-level Input Voltage	V <sub>CC</sub> = 1.65V to 1.95V	0.65 X V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3V to 2.7V	1.7		
		V <sub>CC</sub> = 3V to 3.6V	2		
		V <sub>CC</sub> = 4.5V to 5.5V	0.7 X V <sub>CC</sub>		
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 1.65V to 1.95V		0.35 X V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3V to 2.7V		0.7	
		V <sub>CC</sub> = 3V to 3.6V		0.8	
		V <sub>CC</sub> = 4.5V to 5.5V		0.3 X V <sub>CC</sub>	
V <sub>I</sub>	Input Voltage		0	5.5	V
V <sub>O</sub>	Output Voltage		0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65V		-4	mA
		V <sub>CC</sub> = 2.3V		-8	
		V <sub>CC</sub> = 3V		-16	
		V <sub>CC</sub> = 4.5V		-24	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65V		4	mA
		V <sub>CC</sub> = 2.3V		8	
		V <sub>CC</sub> = 3V		16	
		V <sub>CC</sub> = 4.5V		24	
Δt/ΔV	Input transition rise or fall rate	V <sub>CC</sub> = 1.8V ± 0.15V, 2.5V ± 0.2V		20	ns/V
		V <sub>CC</sub> = 3.3V ± 0.3V		10	
		V <sub>CC</sub> = 5V ± 0.5V		5	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at V<sub>CC</sub> or Ground.

### Electrical Characteristics

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	40°C to 85°C		-40°C to 125°C		Unit	
				Min	Max	Min	Max		
V <sub>OH</sub>	High Level Output Voltage	I <sub>OH</sub> = -100μA	1.65V to 5.5V	V <sub>CC</sub> - 0.1		V <sub>CC</sub> - 0.1		V	
		I <sub>OH</sub> = -4mA	1.65V	1.2		0.95			
		I <sub>OH</sub> = -8mA	2.3V	1.9		1.7			
		I <sub>OH</sub> = -16mA	3V	2.4		1.9			
		I <sub>OH</sub> = -24mA		2.3		2.0			
		I <sub>OH</sub> = -32mA	4.5V	3.8		3.4			
V <sub>OL</sub>	Low Level Output Voltage	I <sub>OL</sub> = 100μA	1.65V to 5.5V		0.1		0.1	V	
		I <sub>OL</sub> = 4mA	1.65V		0.45		0.70		
		I <sub>OL</sub> = 8mA	2.3V		0.3		0.45		
		I <sub>OL</sub> = 16mA	3V			0.4			0.60
		I <sub>OL</sub> = 24mA				0.55			0.80
		I <sub>OL</sub> = 32mA	4.5V			0.55			0.80
I <sub>I</sub>	Input Current	V <sub>I</sub> = 5.5 V or GND	0 to 5.5V		± 5		± 20	μA	
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 5.5V	0		± 10		± 20	μA	
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V of GND I <sub>O</sub> =0	1.65V to 5.5V		10		40	μA	
ΔI <sub>CC</sub>	Additional Supply Current	Input at V <sub>CC</sub> - 0.6V	3 V to 5.5V		500		5000	μA	

### Package Characteristics (All typical values are at V<sub>CC</sub> = 3.3V, T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Typ.	Max	Unit
C <sub>I</sub>	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> - or GND	3.3		4		pF
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	SOT26	(Note 4)		204		°C/W
		SOT363			371		
		DFN1010			430		
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	SOT26	(Note 4)		52		°C/W
		SOT363			143		
		DFN1010			190		

Notes: 4. Test condition for SOT26, SOT363 and DFN1010: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

### Switching Characteristics

$T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $C_L = 30$  or  $50\text{pF}$  (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	$V_{CC} = 1.8\text{V} \pm 0.15\text{V}$		$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		$V_{CC} = 5\text{V} \pm 0.5\text{V}$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pd}$	A	Y	0.5	8.0	1.0	4.4	0.5	4.1	0.5	3.2	ns

$T_A = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $C_L = 30$  or  $50\text{pF}$  (see Figure 1)

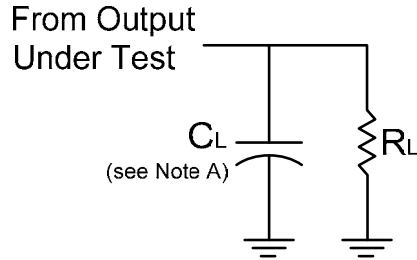
Parameter	From (Input)	TO (OUTPUT)	$V_{CC} = 1.8\text{V} \pm 0.15\text{V}$		$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		$V_{CC} = 5\text{V} \pm 0.5\text{V}$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pd}$	A	Y	0.5	9.5	0.5	5.4	0.5	5.5	0.5	3.8	ns

### Operating Characteristics

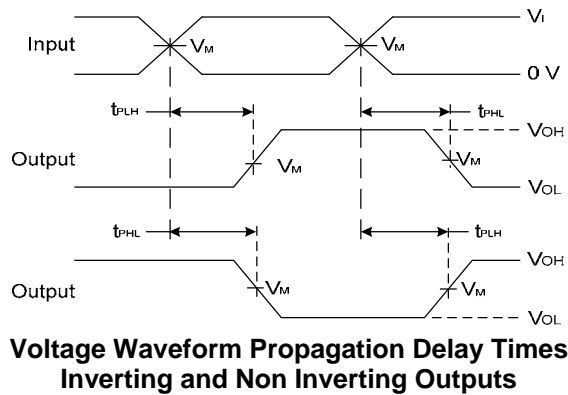
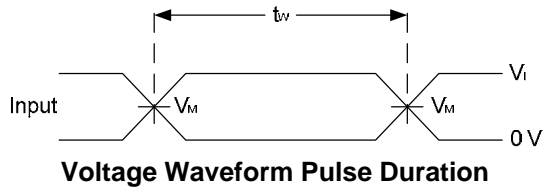
$T_A = 25^{\circ}\text{C}$

Parameter		Test Conditions	$V_{CC} = 1.8\text{V}$	$V_{CC} = 2.5\text{V}$	$V_{CC} = 3.3\text{V}$	$V_{CC} = 5\text{V}$	Unit
			Typ.	Typ.	Typ.	Typ.	
$C_{pd}$	Power dissipation capacitance	$f = 10\text{MHz}$	17	19	20	21	pF

**Parameter Measurement Information**



V <sub>CC</sub>	Inputs		V <sub>M</sub>	C <sub>L</sub>	R <sub>L</sub>
	V <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>			
1.8V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30 pF	1 KΩ
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30 pF	500 Ω
3.3V±0.3V	3V	≤2.5ns	1.5 V	50 pF	500 Ω
5V±0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	50 pF	500 Ω

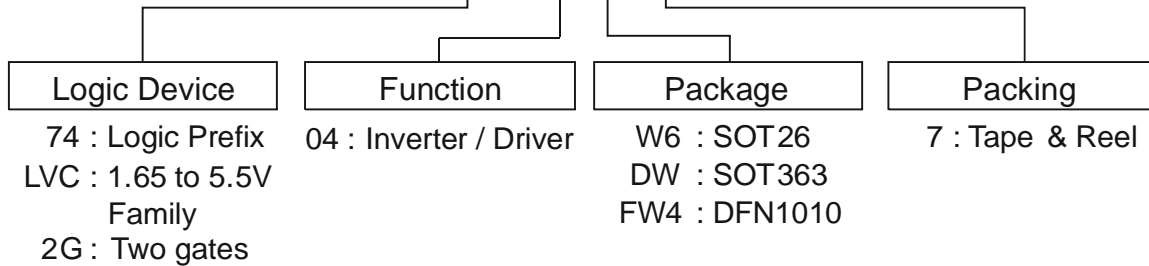


**Figure 1. Load Circuit and Voltage Waveforms**

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

**Ordering Information**

**74LVC2G 04 XX - 7**



Device	Package Code	Packaging (Note 5)	7" Tape and Reel	
			Quantity	Part Number Suffix
74LVC2G04W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC2G04DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC2G04FW4-7	FW4	DFN1010	5000/Tape & Reel	-7



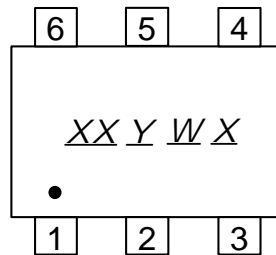
Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.  
6. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

NEW PRODUCT



**Marking Information**

(1) SOT26, SOT363

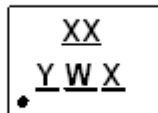


XX : Identification code  
Y : Year 0~9  
W : Week : A~Z : 1~26 week;  
a~z : 27~52 week; z represents  
52 and 53 week  
X : A~Z : Internal Code

Part Number	Package	Identification Code
74LVC2G04W6	SOT26	Z2
74LVC2G04DW	SOT363	Z2

(2) DFN1010

(Top View)

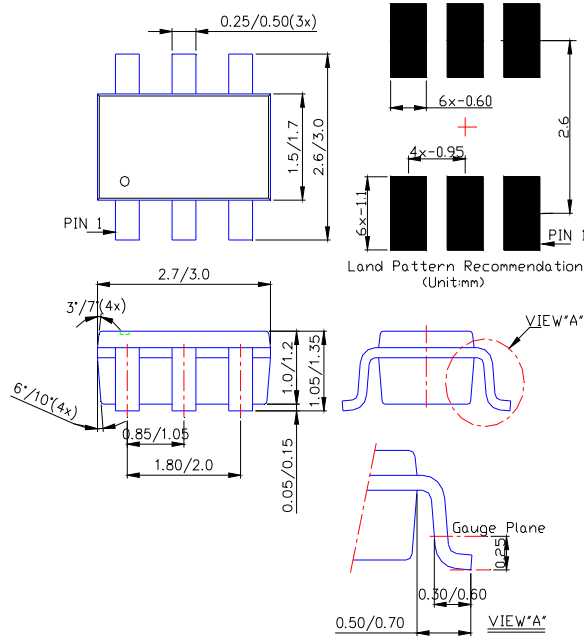


XX : Identification Code  
Y : Year : 0~9  
W : Week : A~Z : 1~26 week;  
a~z : 27~52 week; z represents  
52 and 53 week  
X : A~Z : Internal code

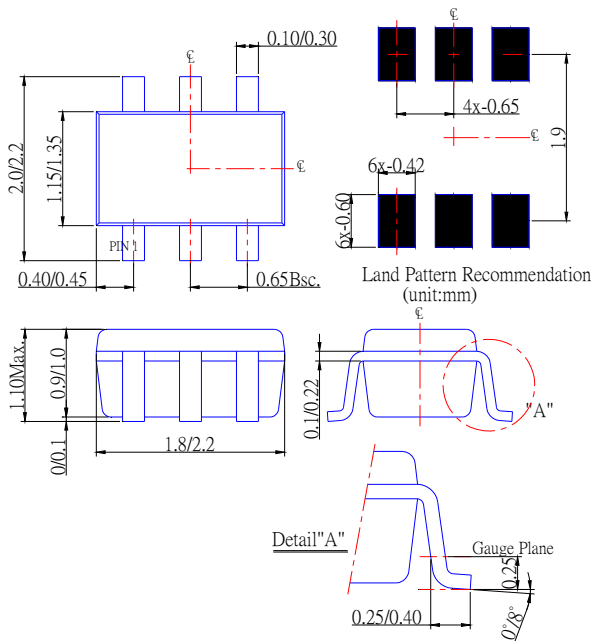
Part Number	Package	Identification Code
74LVC2G04FW4	DFN1010	Z2

**Package Outline Dimensions (All Dimensions in mm)**

**(1) Package Type: SOT26**

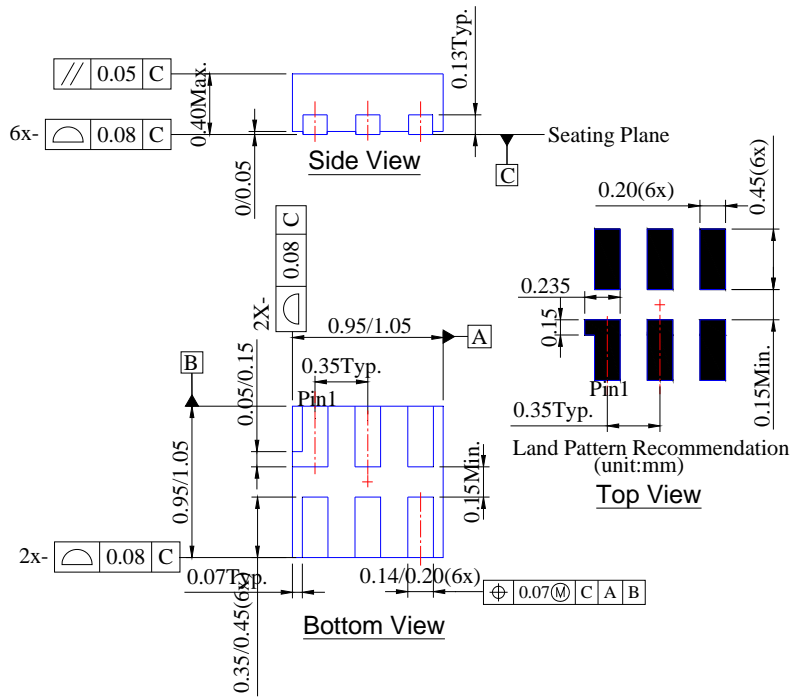


**(2) Package Type: SOT363**



**Package Outline Dimensions (All Dimensions in mm)**

**(3) Package Type: DFN1010**



NEW PRODUCT

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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